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Professional Experience

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| 2015-present | Distinguished Member of Technical Staff, Sandia National Laboratories/CA |
| 2011-present | Adjunct Associate Professor of Materials Science and Engineering, University of Maryland, College Park |
| 2012-2015 | Principal Member of Technical Staff, Sandia National Laboratories/CA. |
| 2009-2012 | Project leader, Nanoelectrochemistry Lab, Center for Nanoscale Science and Technology, NIST/MD. |
| 2002-2009 | Principal Member of Technical Staff, Sandia National Laboratories/CA. |
| 2000-2002 | Section Manager, Materials Characterization Laboratory, Motorola, AZ |
| 1996-2000 | Staff Scientist, Motorola, Tempe, AZ |
| 1995-1996 | Postdoctoral Fellow, Sandia National Laboratories/CA |
| 1993-1994 | DoE Graduate Fellow, Sandia National Laboratories/ CA |
| 1989-1993 | Teaching/research assistant, UCLA |

Education

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|-------------|---|
| 1995 | Ph.D. in Materials Science & Engineering, U C Los Angeles |
| 1989 | BA in Chemistry, U C San Diego |

Awards/Recognition

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| 2022 | Member, <i>Science</i> Board of Reviewing Editors |
| 2017 | Fellow, American Physical Society |
| 2015 | Distinguished Member of Technical Staff |
| 2014 | Sandia National Laboratories Employee Recognition Award |
| 1993 | DoE Graduate Student Fellowship, Sandia National Labs, Livermore, CA |

Selected Publications

Full list: <https://scholar.google.com/citations?user=11-fEDkAAAAJ&hl=en>

Neuromorphic Computing

- E. J. Fuller “Li-ion synaptic transistor for low power analog computing”, *Advanced Materials* 29, 1604310 (2017).
- Y. B. van de Burgt et al., “An organic artificial synapse for low energy neuromorphic computing”, *Nature Materials* 16, 414 (2017)
- E. J. Fuller et al., “Parallel programming of an ionic floating-gate memory array for scalable neuromorphic computing”, *Science* 364, 570, (2019).
- Y. Li et al., “Filament-free bulk resistive memory enables deterministic analogue switching”, *Adv. Materials* 32, 2070339, (2020).

Energy storage materials and devices

- E. J. Fuller et al., “Spatially resolved potential and Li-ion distributions reveal performance-limiting regions in solid-state batteries”, *ACS Energy Lett.*, 6, 3944, 2021.
- D. S. Ashby et al., “Modifying Ionogel Solid-Electrolytes for Complex Electrochemical Systems” *ACS Appl. Mat. Interfaces*, doi.org/10.1021/acsaem.2c02085.
- D. S. Ashby et al, “Understanding the Electrochemical Performance of FeS₂ Conversion Cathodes”, *ACS Appl. Mat. Interfaces*, doi.org/10.1021/acsmi.2c01021.

MOFs and coordination polymers for electronic, photonic and thermoelectric applications

- A. A. Talin, et al., “Tunable Electrical Conductivity in Metal-Organic Framework Thin Film Devices”, *Science* **343**, 66 (2014).
- V. Stavila, et al., “MOF-based electronic and optoelectronic devices”, *Chem. Soc. Reviews* **43**, 5994 (2014).
- K. J. Erickson, et al., “Thin Film Thermoelectric Metal–Organic Framework with High Seebeck Coefficient and Low Thermal Conductivity”, *Adv. Mat.* **27**, 3453 (2015).

Contacts and interfaces

- F. Leonard and A. A. Talin, “Size-dependent effects on electrical contacts to nanotubes and nanowires”, *Phys. Rev. Lett.* **97**, 026804 (2006).
- A. A. Talin et al., “Unusually strong space-charge-limited currents in thin wires”, *Phys. Rev. Lett.* **101**, 076802 (2008).
- F. Leonard and A. A. Talin, “Electrical contacts to one- and two- dimensional nanomaterials”, *Nature Nanotech.* **6**, 773, (2011)
- D. V. Esposito, et al., “Hydrogen Evolution at Si based Metal-Insulator-Semiconductor Photoelectrodes Enhanced by Inversion Channel Charge Collection and Hydrogen Spillover”, *Nature Materials* **12**, 562 (2013).